

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	2632	257/347.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/13 15:41
L2	1116	257/350.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/13 15:41
L3	673	257/351.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/13 15:40
L4	262	257/348.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/13 15:40
L5	4585	((Mosfet or (mos adj fet)) and ((doping or dopant) near2 concentration))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/13 15:40
L6	4282	L5 and (silicon or si)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/13 15:40
L7	78	L6 and ((depleted or depletion) same (fully and partially))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/13 15:40
L8	4585	((Mosfet or (mos adj fet)) and ((doping or dopant) near2 concentration))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/13 15:40

L9	4282	L8 and (silicon or si)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/13 15:40
L10	1908	L9 and (depleted or depletion)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/13 15:46
S4	2477	257/347.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/13 15:40
S5	1	("20040104432").PN.	US-PGPUB	OR	OFF	2005/03/08 15:06
S6	4356	((Mosfet or (mos adj fet)) and ((doping or dopant) near2 concentration))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/08 15:27
S7	4063	S6 and (silicon or si)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/08 15:08
S8	1801	S7 and (depleted or depletion)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/13 15:40
S9	72	S7 and ((depleted or depletion) same (fully and partially))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/10 14:14
S10	2	((Mosfet or (mos adj fet)) WITH (dp and df))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/08 15:28

S11	239	257/348.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/13 15:40
S12	1065	257/350.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/08 17:42
S13	637	257/351.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/08 17:42
S14	21	(US-20040104432-\$ or US-20050006704-\$ or US-20040135204-\$ or US-20040079993-\$ or US-20030227058-\$ or US-20030227056-\$ or US-20010035774-\$ or US-20030071308-\$ or US-20010005030-\$).did. or (US-6835983-\$ or US-6674127-\$ or US-5767549-\$ or US-4183040-\$ or US-6809381-\$ or US-6727552-\$ or US-6268630-\$ or US-6222234-\$ or US-6198132-\$ or US-6100565-\$ or US-6064090-\$ or US-5969385-\$).did.	US-PGPUB; USPAT	OR	OFF	2005/03/10 12:18
S16	20	S14 and (depletion or depleted)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/10 12:18
S17	20	S14 and (concentration)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/10 12:19
S18	243	(Mosfet or (mos adj fet)) and (((depleted or depletion) same ((fully and partially) or (pd and fd))) or ((fully near2 depleted) and (partially near2 depleted)) or (fully-depleted and partially-depleted))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/10 14:20

S19	4364	((Mosfet or (mos adj fet)) and ((doping or dopant) near2 concentration))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/10 14:20
S20	4070	S19 and (silicon or si)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/10 14:20
S21	72	S20 and ((depleted or depletion) same (fully and partially))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/13 15:40
S22	171	S18 not S21	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/10 14:20
S23	240	257/348.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/10 14:21
S24	158	S22 not S23	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/10 14:21